Diode Semiconductor Device - Page 1 of 1



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Glass Overall Length: 0.300 inches Terminal Length: 1.000 inches Overall Diameter: Between 0.138 inches and 0.276 inches Mounting Method: Terminal Features Provided: Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 1600.0 reverse voltage, peak Current Rating Per Characteristic: 360.00 milliamperes forward current, average absolute Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius junction
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Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0